

### **Features**

- · Fast Switching
- · Improved dv/dt Capability
- · Epoxy Meets UL 94 V-0 Flammability Rating
- · Moisture Sensitivity Level 1
- Halogen Free Available Upon Request By Adding Suffix "-HF"
- Lead Free Finish/RoHS Compliant ("P" Suffix Designates RoHS Compliant. See Ordering Information)

## **Maximum Ratings**

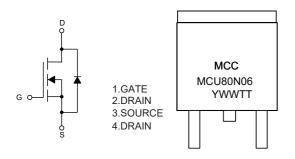
- Operating Junction Temperature Range : -55°C to +175°C
- Storage Temperature Range: -55°C to +175°C
- Thermal Resistance: 1.76°C/W Junction to Case<sup>(Note 1)</sup>

Parameter		Symbol	Rating	Unit
Drain-Source Voltage		V <sub>DS</sub>	60	V
Gate-Source Volltage		$V_{GS}$	±20	V
Continuous Drain Current	T <sub>C</sub> =25°C	- I <sub>D</sub>	80	Α
	T <sub>C</sub> =100°C	'D	56	Α
Pulsed Drain Current		I <sub>DM</sub>	150	Α
Single Pulse Avalanche Energy (Note 2)		E <sub>AS</sub>	290	mJ
Total Power Dissipation		P <sub>D</sub>	85	W

Note: 1.Surface Mounted on FR4 Board, t≤10 sec.

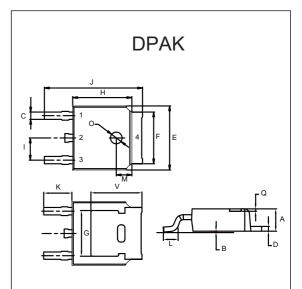
2.EAS Condition:  $T_J$ =25°C, $V_{DD}$ =30V, $V_G$ =10V,L=0.5mH, $R_g$ =25 $\Omega$ .

## **Internal Structure and Marking Code**



YWWTT: 5 codes in total Y is the year WW is the cycle TT is the line type

# N-CHANNEL MOSFET



DIMENSIONS					
DIM INCHES		MM		NOTE	
DIIVI	MIN	MAX	MIN	MAX	NOTE
Α	0.087	0.094	2.20	2.40	
В	0.000	0.005	0.00	0.13	
С	0.026	0.034	0.66	0.86	
D	0.018	0.023	0.46	0.58	
Е	0.256	0.264	6.50	6.70	
F	0.201	0.215	5.10	5.46	
G	0.190		4.83		TYP.
Н	0.236	0.244	6.00	6.20	
ı	0.086	0.094	2.18	2.39	
J	0.386	0.409	9.80	10.40	
K	0.1	14	2.9	90	TYP.
L	0.055	0.067	1.40	1.70	
М	0.063		1.60		TYP.
0	0.043	0.051	1.10	1.30	
Q	0.000	0.012	0.00	0.30	
V	0.211		5.3	35	TYP.



## Electrical Characteristics @ 25°C (Unless Otherwise Specified)

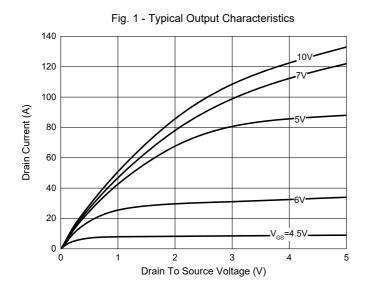
Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit
Static Characteristics						
Drain-Source Breakdown Voltage	V <sub>(BR)DSS</sub>	V <sub>GS</sub> =0V, I <sub>D</sub> =250μA	60			V
Gate-Source Leakage Current	I <sub>GSS</sub>	V <sub>DS</sub> =0V, V <sub>GS</sub> =±20V			±100	nA
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =60V, V <sub>GS</sub> =0V			1	μA
Gate-Threshold Voltage <sup>(Note 3)</sup>	$V_{GS(th)}$	$V_{DS}=V_{GS}$ , $I_{D}=250\mu A$	1	1.6	2.4	V
Drain-Source On-Resistance <sup>(Note 3)</sup>	R <sub>DS(on)</sub>	V <sub>GS</sub> =10V, I <sub>D</sub> =30A		11.3	13	mΩ
Forward Tranconductance <sup>(Note 3)</sup>	<b>g</b> <sub>FS</sub>	V <sub>DS</sub> =10V, I <sub>D</sub> =5.5A	30			S
Dynamic Characteristics(Note 4)			,			
Input Capacitance	C <sub>iss</sub>			2498		
Output Capacitance	C <sub>oss</sub>	$V_{DS}$ =25V, $V_{GS}$ =0V,f=1MHz		185		pF
Reverse Transfer Capacitance	C <sub>rss</sub>			80		
Total Gate Charge	Qg			36		nC
Gate-Source Charge	Q <sub>gs</sub>	V <sub>DS</sub> =30V,V <sub>GS</sub> =10V,I <sub>D</sub> =30A		9.6		
Gate-Drain Charge	$Q_{gd}$			6.6		
Turn-On Delay Time	t <sub>d(on)</sub>			12		
Turn-On Rise Time	t <sub>r</sub>	$V_{DD}$ =30V, $I_D$ =2A, $R_L$ =1 $\Omega$		5.2		
Turn-Off Delay Time	t <sub>d(off)</sub>	$V_{GS}$ =10 $V$ , $R_{GEN}$ =3 $\Omega$		38		ns
Turn-Off Fall Time	t <sub>f</sub>			27		
Drain-Source Body Diode Characteristics						
Continuous Body Diode Current	Is				80	Α
Body Diode Voltage <sup>(Note 3)</sup>	V <sub>SD</sub>	I <sub>S</sub> =20A, V <sub>GS</sub> =0V			1.4	V
Reverse Recovery Time	t <sub>rr</sub>	T <sub>J</sub> =25°C, I <sub>F</sub> =30A,		280		ns
Reverse Recovery Charge	Q <sub>rr</sub>	di/dt=100A/µs <sup>(Note 3)</sup>		2.8		μC
Forward Turn-On Time	t <sub>on</sub>	Intrinsic Turn-On Time is Negligible (Turn-On is Dominated by LS+LD)				

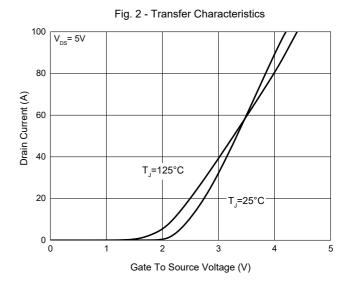
Note 3. Pulse Test : Pulse Width≤300µs, Duty Cycle ≤ 1%.

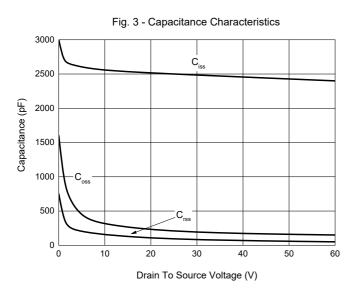
4. Guaranteed by Design, Not Subject to Production Testing.

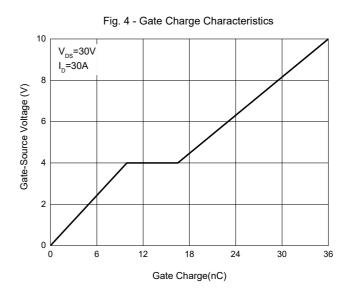


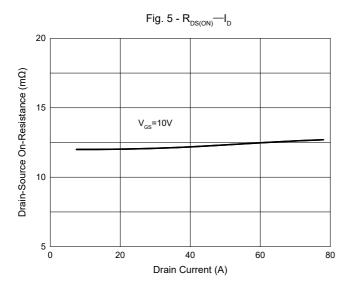
## **Curve Characteristics**

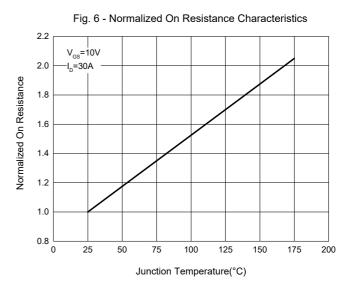














## **Ordering Information**

Device	Packing
Part Number-TP	Tape&Reel: 2.5Kpcs/Reel

Note: Adding "-HF" Suffix for Halogen Free, eg. Part Number-TP-HF

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